

Silicon Diodes

DO-35 Case (Continued)



Low Leakage Diodes

TYPE NO.	V _{RRM} (V) MAX	I _O (mA) MAX	V _F (V) MAX	@ I _F (mA)	I _R @ V _R (nA) MAX	C _T (pF)
1N457A	70	200	1.0	100	25	6.0
1N459A	200	200	1.0	100	25	6.0
1N485B	200	200	1.0	100	25	--
1N3595	150	150	1.0	200	1.0	8.0
CDH300	150	200	1.0	200	1.0	6.0
CDH333	150	200	1.05	200	3.0	6.0



TO-18 (2 Lead) Case

Low Leakage Pico Amp Diode

TYPE NO.	V _{RRM} (V) MAX	I _F (mA) MAX	V _F (V) MAX	@ I _F (mA)	I _R @ V _R (pA) MAX	C _T (pF)
BAV45	35	50	1.0	10	5.0	1.3

Schottky Diodes

DO-35 Case



TYPE NO.	DESCRIPTION	V _{RRM} (VOLTS) MAX	I _O (mA) MAX	V _F (VOLTS) MAX	@ I _F (mA)	t _{rr} (ns) MAX	C _T (pF)
1N6263	Low Current	60	15	0.41	1.0	--	2.2
CDSH-2	High Current	20	200	0.6	200	5.0	--
CDSH-4	High Current	40	200	0.6	200	5.0	--
CDSH-5*	High Current	50	200	0.6	200	5.0	--
CDSH270	High Voltage	100	100	0.45	1.0	--	1.2

DO-35 devices are also available in Radial Tape and Reel (Euroform). See pages 236 thru 238.

* Special Order

(6-December 2004)

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